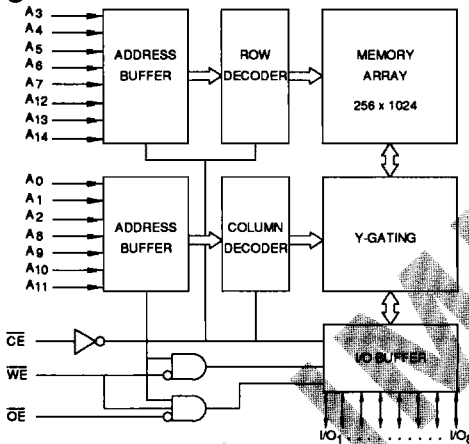


**Features**

- **Low Power**  
 25 mA Maximum (Active)  
 30  $\mu$ A Maximum (Standby)
- **3.3 V  $\pm$  10% Supply**
- **Fully Static: No Clock Required**
- **Two Control Inputs ( $\overline{CE}$  and  $\overline{OE}$ )**
- **TTL Compatible Inputs and Outputs**
- **28-Pin SOIC Surface Mount Packages**
- **JEDEC Pinout**

**Block Diagram**



**256K (32K x 8)  
 Low Voltage  
 CMOS SRAM**

Preliminary

**Description**

The AT38LV256 is a high performance CMOS static Random Access Memory. Its 256K of memory is organized as 32768 words by eight bits. Manufactured with an advanced CMOS technology, the AT38LV256 offers access times down to 70 ns. When the AT38LV256 is deselected, the standby current is just 30  $\mu$ A.

The AT38LV256 powers down to the standby mode when deselected ( $\overline{CE}$  is HIGH). The I/O pins remain in the high impedance state unless the chip is selected ( $\overline{CE}$  is LOW), the outputs are enabled ( $\overline{OE}$  is LOW), and Write Enable is not active ( $\overline{WE}$  is HIGH).

The AT38LV256 is completely TTL compatible and requires a single 3.3-volt power supply. The device is fully static and does not need any clocks or refresh control signals for operation.

**Pin Configurations**

Pin Name	Function
A <sub>0</sub> -A <sub>14</sub>	Addresses
I/O <sub>1</sub> -I/O <sub>8</sub>	Outputs
$\overline{CE}$	Chip Enable
$\overline{OE}$	Output Enable
$\overline{WE}$	Write Enable
V <sub>cc</sub> , GND	Power, Ground

SOIC Top View





## Absolute Maximum Ratings\*

Temperature Under Bias.....	-55° C to 125° C
Storage Temperature.....	-65° C to 150° C
All Input Voltages (including NC Pins) with Respect to Ground .....	-0.3 V <sup>(1)</sup> to V <sub>CC</sub> + 0.3 V
All Output Voltages with Respect to Ground .....	-0.3 V <sup>(1)</sup> to V <sub>CC</sub> + 0.3 V
Maximum Supply Voltage .....	+7.0 V

\*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note:

1. Minimum input voltages are -3.5 V for pulse width less than 20 ns.

## Device Operation

READ: When  $\overline{CE}$  is LOW,  $\overline{OE}$  is LOW, and  $\overline{WE}$  is HIGH, the eight bits of data stored at the memory location determined by the address input (pins A<sub>0</sub> through A<sub>14</sub>) are inserted on the data outputs (pins I/O<sub>1</sub> through I/O<sub>8</sub>).

WRITE: When  $\overline{CE}$  is LOW and  $\overline{WE}$  is LOW, the eight bits of data placed on the input pins (I/O<sub>1</sub> through I/O<sub>8</sub>) are stored at the memory location determined by the address input (pins A<sub>0</sub> through A<sub>14</sub>).

## Operating Modes

MODE/PIN	$\overline{CE}$	$\overline{OE}$	$\overline{WE}$	I/O
Read	L	L	H	DOUT
Write	L	X <sup>(1)</sup>	L	DIN
Standby (Not Selected)	H	X	X	High Z
Output Disable (High Impedance)	X	H	X	High Z

Note: 1. X can be L (Low) or H (High)

## D.C. and A.C. Operating Range

		AT38LV256
Operating Temperature (Ambient)	Commercial	0°C - 70°C
V <sub>CC</sub> Power Supply		3.3 V ± 10%

D.C. and Operating Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Units
I <sub>LI</sub>	Input Load Current	V <sub>IN</sub> = 0 to V <sub>CC</sub>			2	μA
I <sub>LO</sub>	Output Leakage Current	$\overline{CE} = 2.2\text{ V to }V_{CC} + 0.3\text{ V or}$ $\overline{OE} = 2.2\text{ V to }V_{CC} + 0.3\text{ V or}$ $\overline{WE} = -0.3\text{ V to }0.8\text{ V}$ V <sub>I/O</sub> = 0 to V <sub>CC</sub>			30	μA
I <sub>SB1</sub>	Standby Current (CMOS)	$\overline{CE} \geq V_{CC} - 0.2\text{ V,}$ V <sub>IN</sub> = (V <sub>CC</sub> - 0.2 V) or ≤ 0.2 V			30	μA
I <sub>SB2</sub>	Standby Current (TTL)	$\overline{CE} = 2.2\text{ V to }V_{CC} + 0.3\text{ V,}$ V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>			2.5	mA
I <sub>CC</sub>	V <sub>CC</sub> Active Current (TTL)	$\overline{CE} = -0.3\text{ V to }0.5\text{ V,}$ I <sub>OUT</sub> = 0 mA, min cycle			25	mA
V <sub>IL</sub> <sup>(1)</sup>	Input Low Voltage		-0.3 <sup>(2)</sup>		0.5	V
V <sub>IH</sub> <sup>(1)</sup>	Input High Voltage		2.2 V		V <sub>CC</sub> + 0.3	V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 1.0 mA			0.4	V
V <sub>OH</sub>	Output High Voltage	I <sub>OH</sub> = -0.5 mA	2.4			V

Note: 1. These are voltages with respect to device GND.  
2. V<sub>IL</sub> = -3.0 V for pulse width less than 20 ns.

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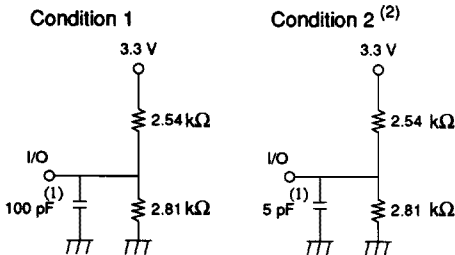
Pin Capacitance (f = 1 MHz, T = 25°C)<sup>(1)</sup>

Symbol	Parameter	Conditions	Min	Max	Units
C <sub>OUT</sub>	Input/Output Capacitance	V <sub>OUT</sub> = 0 V		10	pF
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0 V		10	pF

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested.

Output Test Load

Figure 1



Item	Condition
Input pulse "High" level	V <sub>IH</sub> = 3.0 V
Input pulse "Low" level	V <sub>IL</sub> = 0 V
Input rise time	t <sub>R</sub> = 5 ns
Input fall time	t <sub>F</sub> = 5 ns
Input and output reference level	1.5 V
Output load	See Figure 1

Notes: 1. Capacitance Load includes scope and jig capacitances.  
2. For t<sub>COE</sub>, t<sub>OOE</sub>, t<sub>COD</sub>, t<sub>OOD</sub>, t<sub>WOE</sub>, t<sub>WOD</sub>.



## A.C. Characteristics for Read

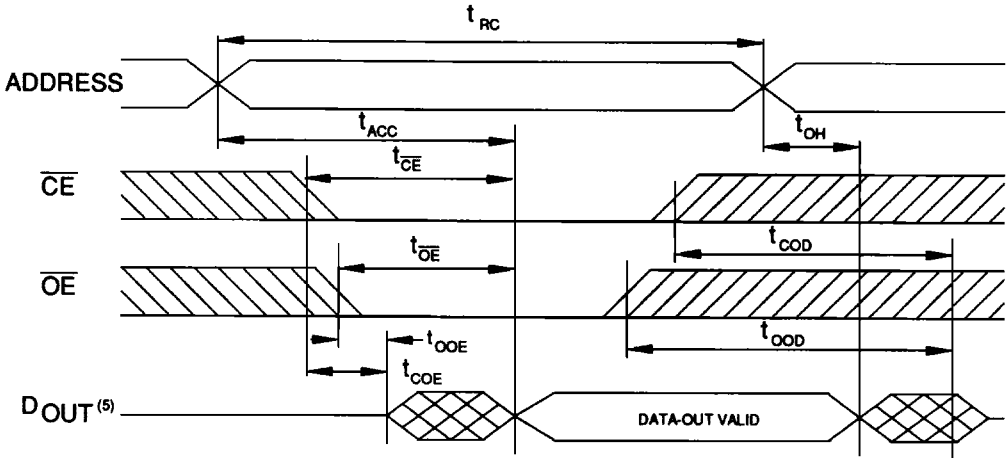
Symbol	Parameter	AT38LV256-70		AT38LV256-12		Units
		Min	Max	Min	Max	
t <sub>RC</sub>	Read Cycle Time	70		120		ns
t <sub>ACC</sub>	Address Access Time		70		120	ns
t <sub>CE</sub>	$\overline{\text{CE}}$ Access Time		70		120	ns
t <sub>OE</sub>	$\overline{\text{OE}}$ Access Time		35		60	ns
t <sub>OH</sub>	Output Hold Time	10		10		ns
t <sub>COE</sub> <sup>(1)</sup>	$\overline{\text{CE}}$ Output Enable Time	10		10		ns
t <sub>OOE</sub> <sup>(1)</sup>	$\overline{\text{OE}}$ Output Enable Time	5		5		ns
t <sub>CO<math>\overline{\text{D}}</math></sub> <sup>(1)</sup>	$\overline{\text{CE}}$ Output Disable Time		30		40	ns
t <sub>OO<math>\overline{\text{D}}</math></sub> <sup>(1)</sup>	$\overline{\text{OE}}$ Output Disable Time		30		40	ns

## A.C. Characteristics for Write

Symbol	Parameter	AT38LV256-70		AT38LV256-12		Units
		Min	Max	Min	Max	
t <sub>WC</sub>	Write Cycle Time	70		120		ns
t <sub>AS</sub>	Address Setup Time	0		0		ns
t <sub>WP</sub>	Write Pulse Width	45		100		ns
t <sub>CS</sub>	$\overline{\text{CE}}$ Setup Time	70		110		ns
t <sub>WR</sub>	Write Recovery Time	5		5		ns
t <sub>DS</sub>	Data Setup Time	30		70		ns
t <sub>DH</sub>	Data Hold Time	0		0		ns
t <sub>WOE</sub> <sup>(1)</sup>	$\overline{\text{WE}}$ Output Enable Time	10		10		ns
t <sub>WOD</sub> <sup>(1)</sup>	$\overline{\text{WE}}$ Output Disable Time		30		40	ns

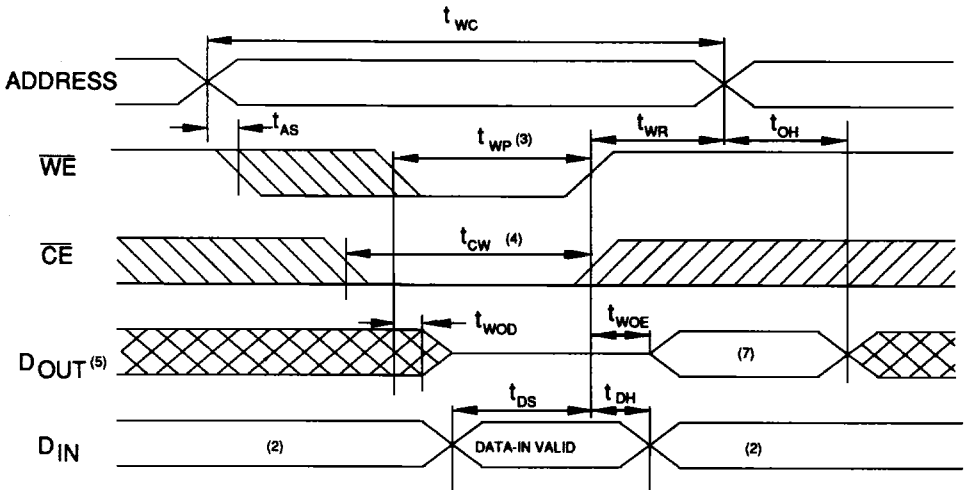
Note: 1. Transition is measured by  $\pm 500$  mV from the normal state with the output test load circuit, condition 2.  
This parameter is sampled and is not 100% tested.

A.C. Waveforms for Read Cycle <sup>(1)</sup>

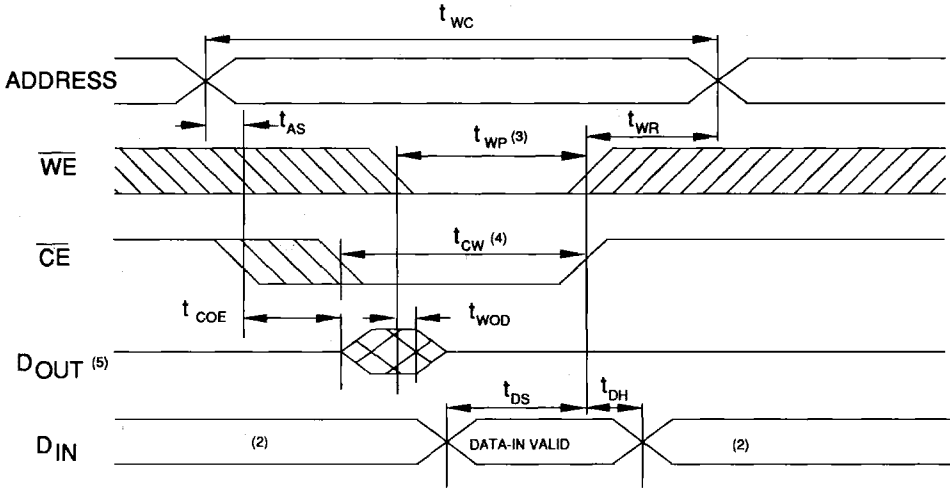


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A.C. Waveforms for Write Cycle 1 ( $\overline{WE}$  Write) <sup>(6)</sup>



### A.C. Waveforms for Write Cycle 2 ( $\overline{WE}$ Write) <sup>(6)</sup>



**Notes:**

1. During a Read Cycle,  $\overline{WE}$  should be HIGH.
2. During this period, I/O pins are in the output state.
3. A Write occurs when  $\overline{CE}$  and  $\overline{WE}$  are LOW at the same time. A Write begins at the latest transition among  $\overline{CE}$  going LOW, and  $\overline{WE}$  going LOW. A Write ends at the earliest transition among  $\overline{CE}$  going HIGH, and  $\overline{WE}$  going HIGH.  $t_{WP}$  is measured from the beginning of Write to the end of Write.
4.  $t_{CW}$  is measured from the later of  $\overline{CE}$  going LOW or going HIGH to the end of Write.
5. If  $\overline{CE}$  or  $\overline{OE}$  is HIGH, or  $\overline{WE}$  is LOW,  $D_{OUT}$  goes to a high impedance state.
6. During a write cycle,  $\overline{OE} = V_{IH}$  or  $V_{IL}$ .
7.  $D_{OUT}$  is equal to the Input Data written during the same cycle.

**Ordering Information**

t <sub>ACC</sub> (ns)	I <sub>CC</sub> (mA)		Ordering Code	Package	Operation Range
	Active	Standby			
70	25	0.03	AT38LV256-70RC	28R	Commercial (0° to 70°C)
120	25	0.03	AT38LV256-12RC	28R	Commercial (0° to 70°C)

Package Type	
<b>28R</b>	28 Lead, 0.330" Wide, Plastic Gull Wing Small Outline (SOIC)

